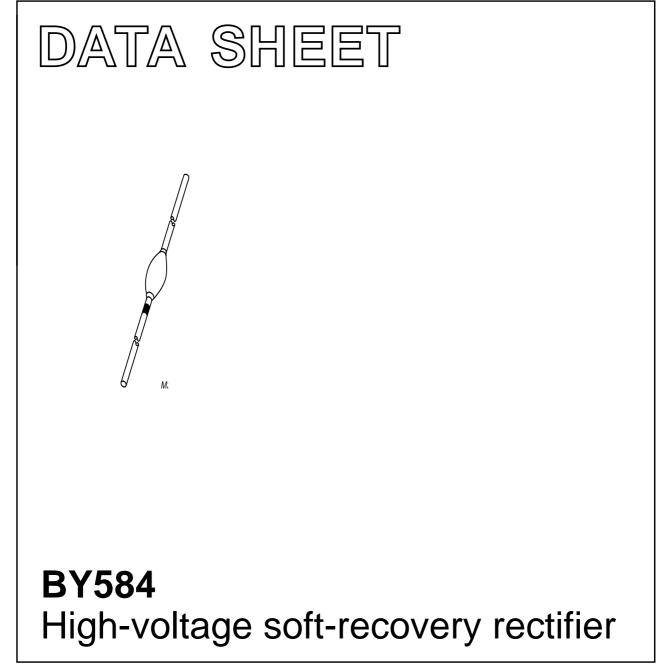
# DISCRETE SEMICONDUCTORS



Product specification Supersedes data of May 1996 1996 Sep 26



1996 Sep 26

## High-voltage soft-recovery rectifier

DESCRIPTION

Rugged glass package, using a high

This package is hermetically sealed

temperature alloyed construction.

and fatigue free as coefficients of

#### FEATURES

- · Glass passivated
- · High maximum operating temperature
- · Low leakage current
- · Excellent stability
- Soft-recovery switching characteristics
- · Compact construction.

### **APPLICATIONS**

- Grid 2 supply in colour television picture tubes
- High-voltage applications for:
  - High frequencies
  - Switching applications.

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL             | PARAMETER                           | CONDITIONS   | MIN. | MAX. | UNIT |
|--------------------|-------------------------------------|--|------|------|------|
| V <sub>RSM</sub>   | non-repetitive peak reverse voltage |  | -    | 1800 | V    |
| V <sub>RRM</sub>   | repetitive peak reverse voltage     |  | -    | 1800 | V    |
| V <sub>RW</sub>    | working reverse voltage             |  | _    | 1500 | V    |
| I <sub>F(AV)</sub> | average forward current             | averaged over any 20 ms period;<br>$T_{tp} = 25 \text{ °C}$ ; lead length = 10 mm;<br>see Fig.2; see also Fig.4              | _    | 85   | mA   |
|                    |                                     | averaged over any 20 ms period;<br>T <sub>amb</sub> = 60 °C; PCB mounting<br>(see Fig.6); see Fig.3;<br>see also Fig.4       | _    | 50   | mA   |
| I <sub>FRM</sub>   | repetitive peak forward current     |  | -    | 800  | mA   |
| I <sub>FSM</sub>   | non-repetitive peak forward current | t $\leq$ 10 ms; half sinewave;<br>T <sub>j</sub> = T <sub>j max</sub> prior to surge;<br>V <sub>R</sub> = V <sub>RWmax</sub> | -    | 5    | A    |
| T <sub>stg</sub>   | storage temperature                 |  | -65  | +120 | °C   |
| Tj                 | junction temperature                |  | -65  | +120 | °C   |

### **Product specification**

### expansion of all used parts are matched.

The package is designed to be used in an insulating medium such as resin, oil or SF6 gas.

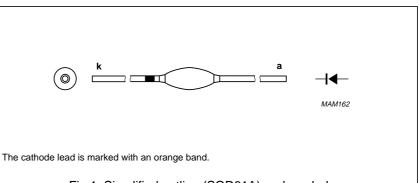


Fig.1 Simplified outline (SOD61A) and symbol.

**BY584** 

# High-voltage soft-recovery rectifier

### BY584

### **ELECTRICAL CHARACTERISTICS**

 $T_j = 25 \ ^{\circ}C$ ; unless otherwise specified.

| SYMBOL          | PARAMETER             | CONDITIONS   | MIN. | TYP. | MAX. | UNIT |
|-----------------|-----------------------|--|------|------|------|------|
| V <sub>F</sub>  | forward voltage       | $I_F = 100 \text{ mA}; T_j = T_{j \text{ max}}; \text{ see Fig.5}$                         | _    | _    | 8.5  | V    |
| I <sub>R</sub>  | reverse current       | $V_{R} = V_{RWmax}; T_{j} = T_{j max}$   | _    | -    | 3    | μA   |
| Qr              | recovery charge       | when switched from $I_F$ = 100 mA to $V_R \ge 100$ V and $dI_F/dt$ = –200 mA/µs; see Fig.7 | _    | _    | 1    | nC   |
| t <sub>f</sub>  | fall time             | when switched from $I_F$ = 100 mA to $V_R \ge 100$ V and $dI_F/dt$ = -200 mA/µs; see Fig.7 | 100  | -    | _    | ns   |
| t <sub>rr</sub> | reverse recovery time | when switched from $I_F$ = 100 mA to $V_R \ge 100$ V and $dI_F/dt$ = –200 mA/µs; see Fig.7 | _    | 200  | _    | ns   |
| C <sub>d</sub>  | diode capacitance     | V <sub>R</sub> = 0 V; f = 1 MHz  | _    | 2    | _    | pF   |

### THERMAL CHARACTERISTICS

| SYMBOL               | PARAMETER                                     | CONDITIONS          | VALUE | UNIT |
|----------------------|---|---------------------|-------|------|
| R <sub>th j-tp</sub> | thermal resistance from junction to tie-point | lead length = 10 mm | 100   | K/W  |
| R <sub>th j-a</sub>  | thermal resistance from junction to ambient   | note 1              | 155   | K/W  |

Note

1. Device mounted on epoxy-glass printed-circuit board, 1.5 mm thick; thickness of copper ≥40 μm, see Fig.6. For more information please refer to the *"General Part of associated Handbook"*.

MBH400

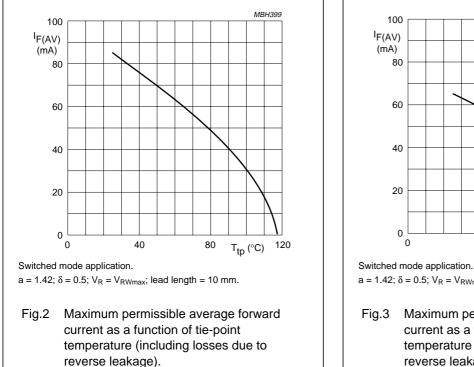
T<sub>amb</sub> (°C) 120

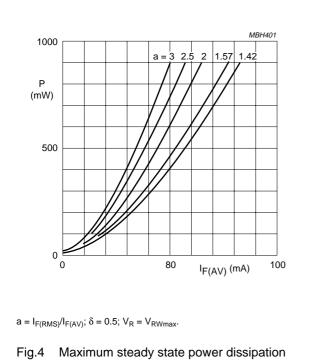
80

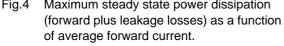
## High-voltage soft-recovery rectifier

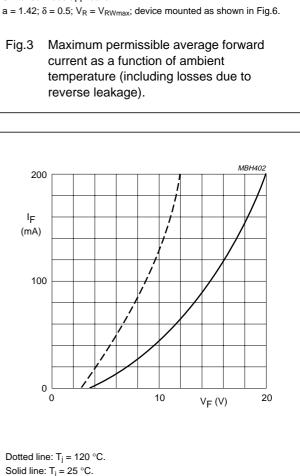
## BY584

#### **GRAPHICAL DATA**







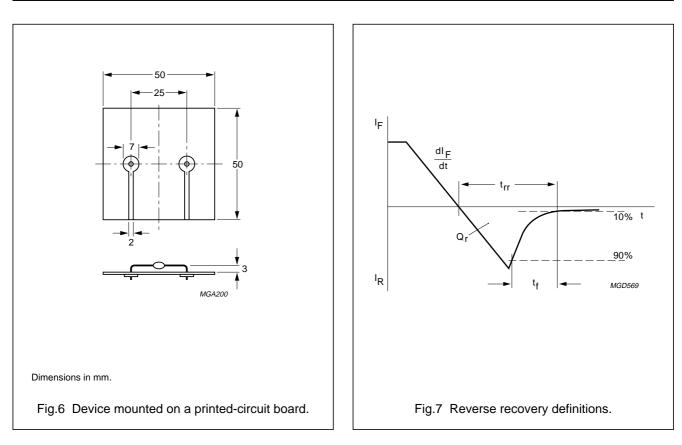


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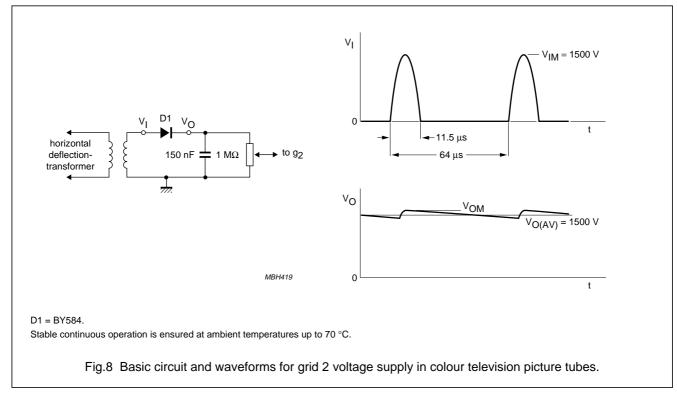
Fig.5 Forward current as a function of maximum forward voltage.

# High-voltage soft-recovery rectifier

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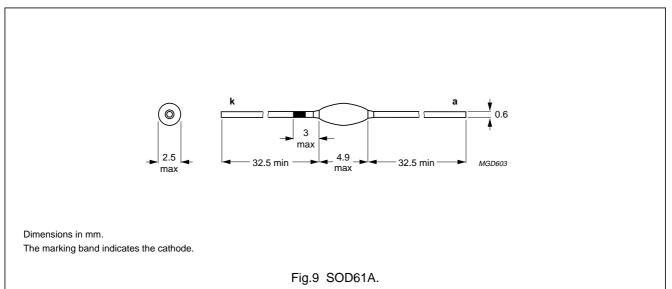
### **APPLICATION INFORMATION**



## High-voltage soft-recovery rectifier

## BY584

#### PACKAGE OUTLINE



#### DEFINITIONS

| Data Sheet Status           |  |
|-----------------------------|--|
| Objective specification     | This data sheet contains target or goal specifications for product development.  |
| Preliminary specification   | This data sheet contains preliminary data; supplementary data may be published later.  |
| Product specification       | This data sheet contains final product specifications.   |
| Limiting values             |  |
| more of the limiting values | accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or<br>may cause permanent damage to the device. These are stress ratings only and operation |
|                             | any other conditions above those given in the Characteristics sections of the specification limiting values for extended periods may affect device reliability.            |
|                             |  |

### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.